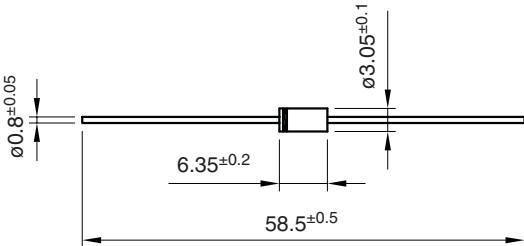


## 2 Amp. Glass Passivated Avalanche Ultrafast Recovery Rectifier

<p>Dimensions in mm.</p>  <p><b>DO-15 (Plastic)</b></p> <p>Mounting instructions</p> <ol style="list-style-type: none"> <li>Min. distance from body to soldering point, 4 mm.</li> <li>Max. solder temperature, 350 °C.</li> <li>Max. soldering time, 3.5 sec.</li> <li>Do not bend lead at a point closer than 2 mm. to the body.</li> </ol>	<p><b>Voltage</b> 50 to 600 V</p> <p><b>Current</b> 2 A at 55 °C</p>  <ul style="list-style-type: none"> <li>Glass passivated junction</li> <li>High current capability</li> <li>The plastic material carries U/L recognition 94 V-0</li> <li>Terminals: Axial Leads</li> <li>Polarity: Color band denotes cathode</li> </ul>
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### Maximum Ratings, according to IEC publication No. 134

		EGP20A	EGP20B	EGP20D	EGP20F	EGP20G	EGP20J
$V_{RRM}$	Peak Recurrent Reverse Voltage (V)	50	100	200	300	400	600
$V_{RMS}$	Maximum RMS Voltage (V)	35	70	140	210	280	420
$V_{DC}$	Maximum DC Blocking Voltage (V)	50	100	200	300	400	600
$I_{F(AV)}$	Forward current at $T_{amb} = 55^{\circ}\text{C}$				2 A		
$I_{FRM}$	Recurrent peak forward current				20 A		
$I_{FSM}$	8.3 ms. peak forward surge current (Jedec Method)				75 A		
$t_{rr}$	Max. reverse recovery time from $I_F = 0.5 \text{ A} ; I_R = 1 \text{ A} ; I_{RR} = 0.25 \text{ A}$				50 ns		
$C_j$	Typical Junction Capacitance at 1 MHz and Reverse Voltage of $4V_{DC}$		45 pF			30 pF	
$T_j$	Operating temperature range				-65 to + 150 °C		
$T_{stg}$	Storage temperature range				-65 to + 150 °C		
$E_{RSM}$	Maximum non repetitive peak reverse avalanche energy $I_R = 1 \text{ A} ; T_j = 25^{\circ}\text{C}$				20 mJ		

### Electrical Characteristics at $T_{amb} = 25^{\circ}\text{C}$

$V_F$	Maximum forward voltage drop at $I_F = 2 \text{ A}$	0.95 V	1.25 V
$I_R$	Max. reverse current at $V_{RRM}$	at 25 °C 5 µA	at 150 °C 50 µA
$R_{th(j-a)}$	Max. thermal resistance ( $I = 10\text{mm}$ )		30 °C/W

## Rating And Characteristic Curves

